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## BIB DATA SHEET

CONFIRMATION NO. 8948

SERIAL NUMBER	FILING or 371(c) DATE	CLASS	GROUP ART UNIT	ATTORNEY DOCKET NO.
10/574,202	03/31/2006 RULE	257	2815	Q77895
<b>APPLICANTS</b> Masato Kobayakawa, Chiba-shi, Chiba, JAPAN; Hideki Tomozawa, Chiba-shi, Chiba, JAPAN; Mineo Okuyama, Chiba-shi, Chiba, JAPAN;				
<b>** CONTINUING DATA *****</b> This application is a 371 of PCT/JP04/14873 10/01/2004 which claims benefit of 60/509,997 10/10/2003				
<b>** FOREIGN APPLICATIONS *****</b> JAPAN 2003-344599 10/02/2003				
<b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 10/06/2006				
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No 35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No Verified and Acknowledged <u>/JAMI M VALENTINE/</u> Examiner's Signature	<input type="checkbox"/> Met after Allowance Initials	<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWINGS</b> 3	<b>TOTAL CLAIMS</b> 30
<b>INDEPENDENT CLAIMS</b> 2				
<b>ADDRESS</b> SUGHRUE MION, PLLC 2100 PENNSYLVANIA AVENUE, N.W. SUITE 800 WASHINGTON, DC 20037 UNITED STATES				
<b>TITLE</b> Nitride semiconductor; light-emitting device, light-emitting diode, laser device and lamp using the semiconductor; and production methods thereof				
<b>FILING FEE RECEIVED</b> 1400	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:			<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit